



12N25

Power MOSFET

12A, 250V N-CHANNEL POWER MOSFET

DESCRIPTION

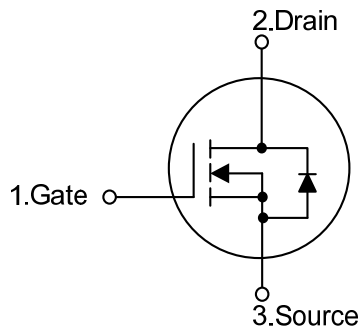
The UTC **12N25** is an N-channel mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology specializes in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

The UTC **12N25** is universally applied in electronic lamp ballast based on half bridge topology and high efficient switched mode power supply.

FEATURES

- * $I_D = 12A$
- * $V_{DS} = 250V$
- * $R_{DS(ON)} = 0.34\Omega @ V_{GS} = 10V$
- * High switching speed
- * 100% avalanche tested

SYMBOL

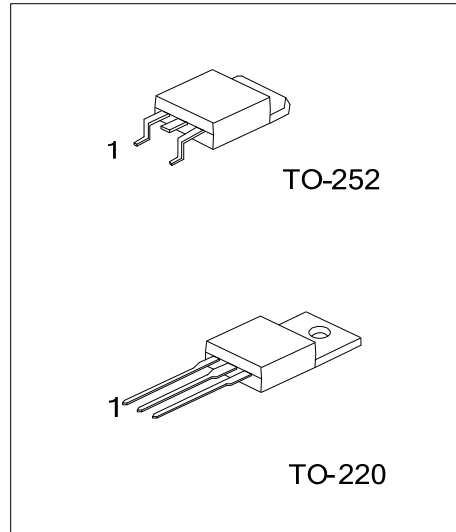


ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
12N25L-TA3-T	12N25G-TA3-T	TO-220	G	D	S	Tube
12N25L-TN3-T	12N25G-TN3-T	TO-252	G	D	S	Tube
12N25L-TN3-R	12N25G-TN3-R	TO-252	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

12N25L-TA3-T (1) Packing Type (2) Package Type (3) Lead Free	(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TN3: TO-252 (3) L: Lead Free, G: Halogen Free
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■ ABSOLUTE MAXIMUM RATINGS ($T_C=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	250	V
Gate-Source Voltage		V_{GSS}	± 20	V
Drain Current	Continuous ($T_C=25^\circ\text{C}$)	I_D	12	A
	Pulsed (Note 2)	I_{DM}	48	A
Single Pulsed Avalanche Energy		E_{AS}	474	mJ
Power Dissipation	TO-220	P_D	73	W
	TO-252		30	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature Range		T_{STG}	-55~+150	$^\circ\text{C}$

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220	θ_{JA}	62.5	$^\circ\text{C/W}$
	TO-252		100	$^\circ\text{C/W}$
Junction to Case	TO-220	θ_{JC}	1.7	$^\circ\text{C/W}$
	TO-252		4.1	$^\circ\text{C/W}$

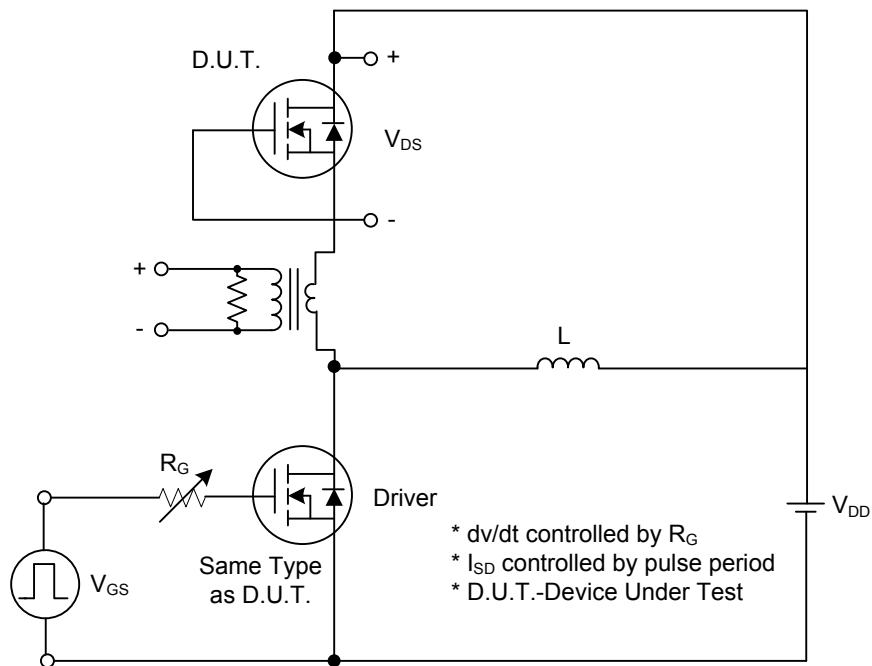
■ ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$, unless otherwise noted)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	I _D =250μA, V _{GS} =0V	250			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =250V, V _{GS} =0V			1	μA
Gate- Source Leakage Current	Forward	I _{GSS}	V _{GS} =+20V, V _{DS} =0V			+100	nA
	Reverse		V _{GS} =-20V, V _{DS} =0V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	2.0		4.0	V
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =12A		0.34	0.5	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C _{ISS}	V _{GS} =0V, V _{DS} =25V, f=1.0MHz			3000	pF
Output Capacitance		C _{OSS}				900	pF
Reverse Transfer Capacitance		C _{RSS}				400	pF
SWITCHING PARAMETERS							
Turn-ON Delay Time		t _{D(ON)}	V _{DD} =200V, I _D =12A, R _G =25Ω (Note 1, 2)		14	50	ns
Rise Time		t _R			80	150	ns
Turn-OFF Delay Time		t _{D(OFF)}			90	200	ns
Fall-Time		t _F			80	170	ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Drain-Source Diode Forward Voltage		V _{SD}	I _S =12A, V _{GS} =0V			1.4	V
Maximum Body-Diode Continuous Current		I _S				12	A
Maximum Body-Diode Pulsed Current		I _{SM}				48	A

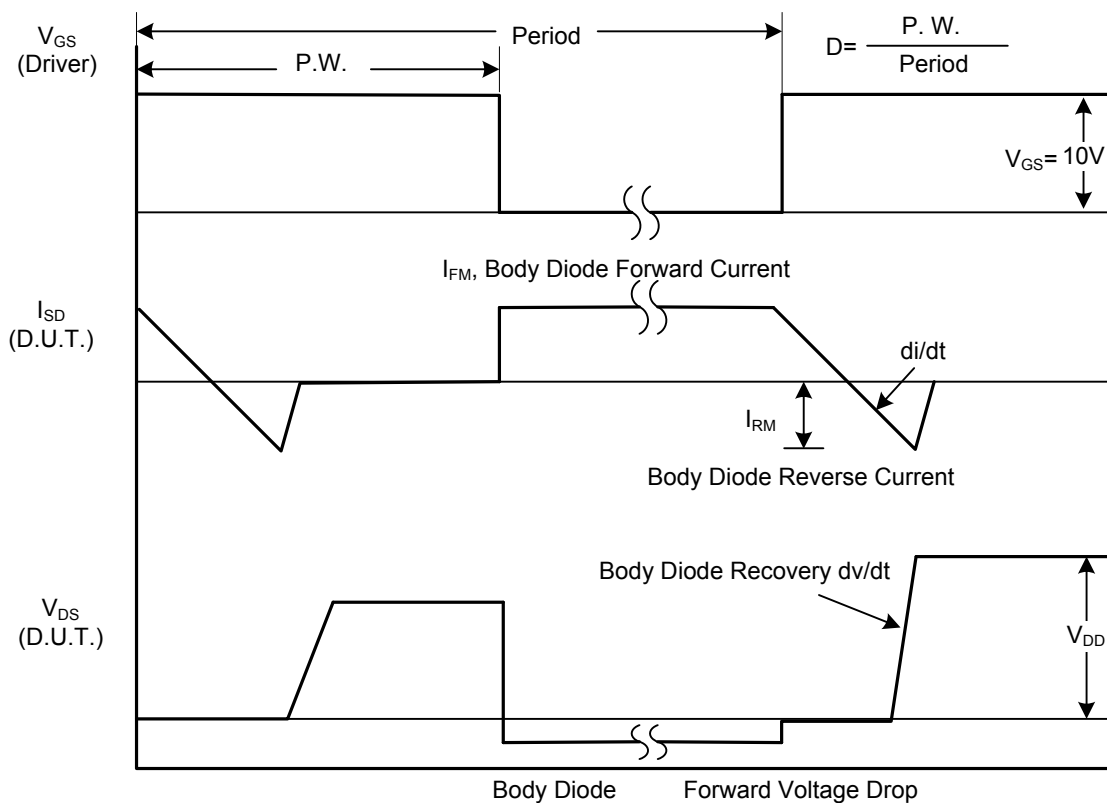
Notes: 1. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$

2. Essentially independent of operating temperature

■ TEST CIRCUITS AND WAVEFORMS

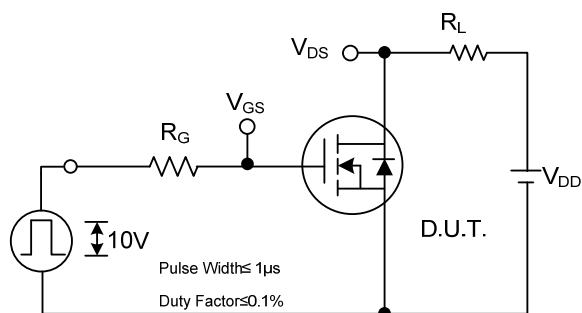


Peak Diode Recovery dv/dt Test Circuit

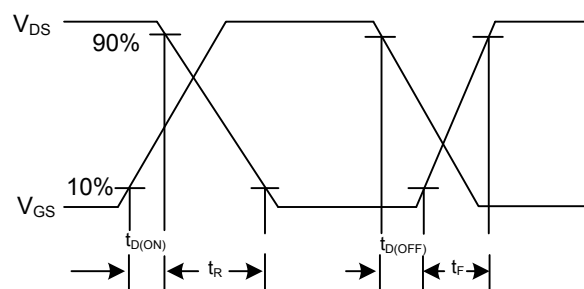


Peak Diode Recovery dv/dt Waveforms

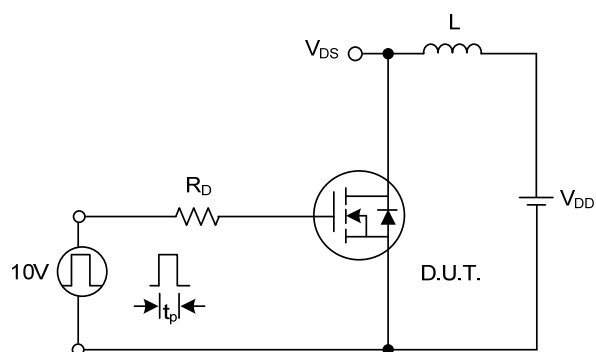
■ TEST CIRCUITS AND WAVEFORMS (Cont.)



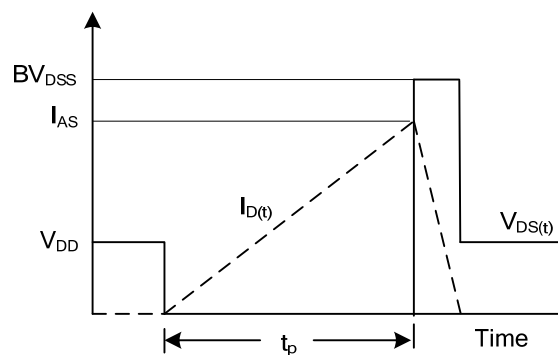
Switching Test Circuit



Switching Waveforms

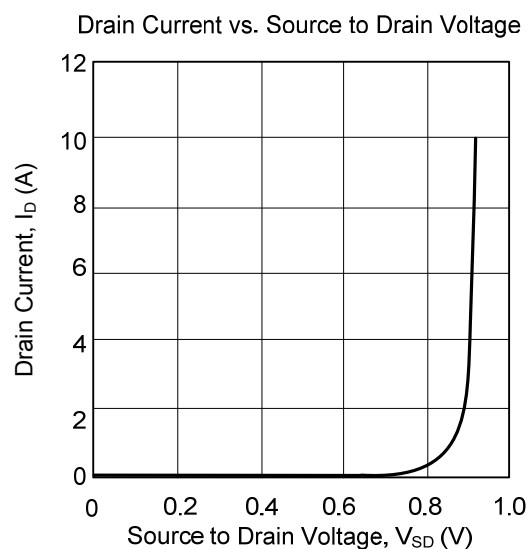
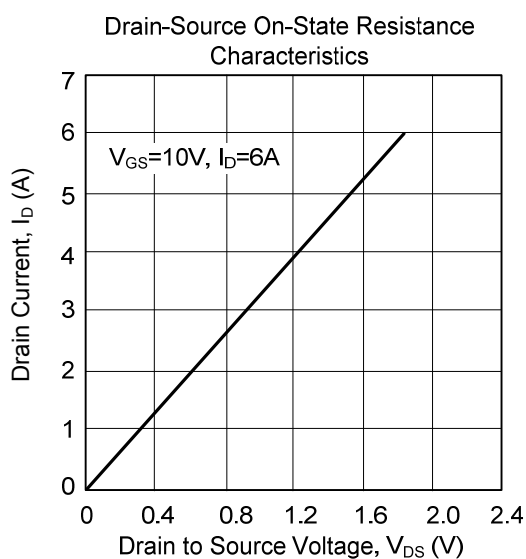
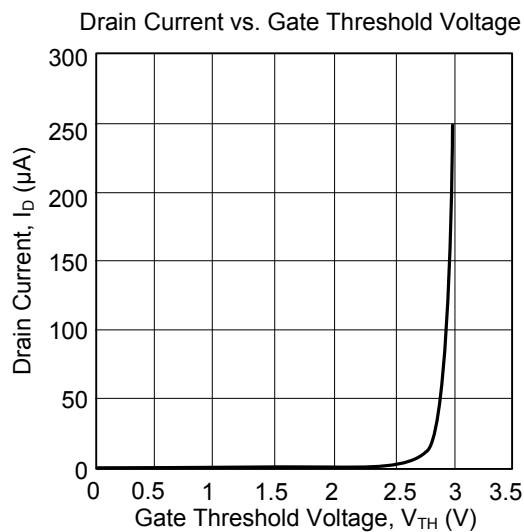
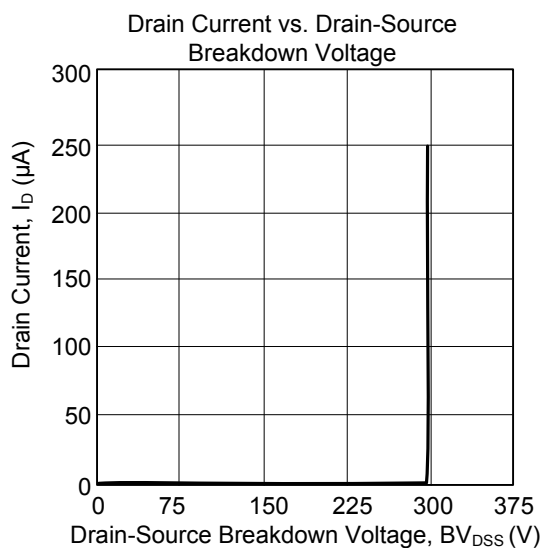


Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

■ TYPICAL CHARACTERISTICS



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